

# HD74ALVC2G06

## Triple Inverter Buffers / Drivers with Open Drain

REJ03D0162-0500 Rev.5.00 Sep 08, 2006

#### **Description**

The HD74ALVC2G06 has triple inverter buffers / drivers with open drain outputs in an 8 pin package. Low voltage and high-speed operation is suitable for the battery powered products (e.g., notebook computers), and the low power consumption extends the battery life.

#### **Features**

- The basic gate function is lined up as Renesas uni logic series.
- Supplied on emboss taping for high-speed automatic mounting.
- Supply voltage range: 1.2 to 3.6 V
- Operating temperature range: -40 to +85°C
- All inputs  $V_{IH}$  (Max.) = 3.6 V (@ $V_{CC}$  = 0 V to 3.6 V)
- All outputs  $V_0$  (Max.) = 3.6 V (@ $V_{CC}$  = 0 V, Output: Z)
- Output current  $2 \text{ mA} (@V_{CC} = 1.2 \text{ V})$

 $4 \text{ mA} (@V_{CC} = 1.4 \text{ V to } 1.6 \text{ V})$ 

6 mA (@ $V_{CC} = 1.65 \text{ V}$  to 1.95 V)

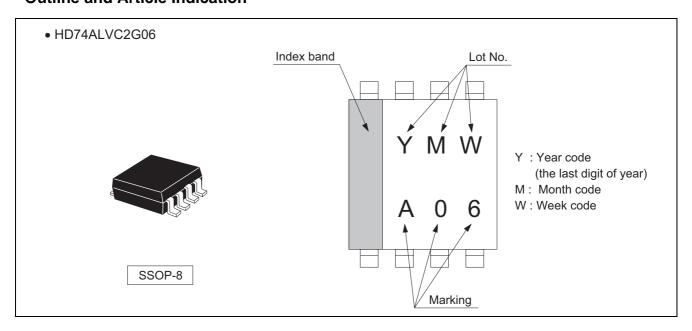
18 mA (@ $V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$ )

24 mA (@ $V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$ )

• Ordering Information

Part Name	Package Type	Package Code (Previous Code)	Package Abbreviation	Taping Abbreviation (Quantity)
HD74ALVC2G06USE	SSOP-8 pin	PVSP0008KA-A (TTP-8DBV)	US	E (3,000 pcs/reel)

#### **Outline and Article Indication**



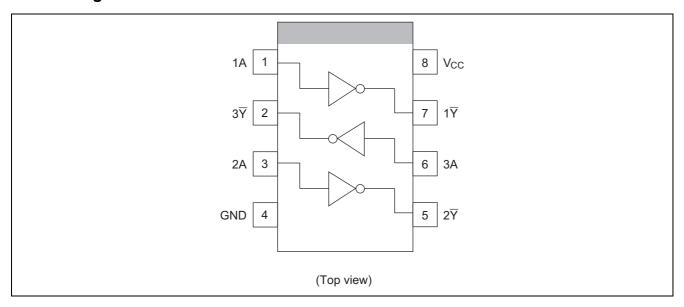
#### **Function Table**

Input A	Output ₹
L	Z
Н	L

H: High level L: Low level

Z: High impedance

#### **Pin Arrangement**



#### **Absolute Maximum Ratings**

Item	Symbol	Ratings	Unit	Conditions
Supply voltage range	V <sub>CC</sub>	-0.5 to 4.6	V	
Input voltage range *1	Vı	-0.5 to 4.6	V	
Output voltage range *1, 2	Vo	-0.5 to V <sub>CC</sub> +0.5	V	Output : L
Output voltage range	Vo	-0.5 to 4.6	V	V <sub>CC</sub> : OFF or Output: Z
Input clamp current	I <sub>IK</sub>	-50	mA	V <sub>1</sub> < 0
Output clamp current	I <sub>OK</sub>	-50	mA	V <sub>O</sub> < 0
Continuous output current	I <sub>O</sub>	±50	mA	$V_O = 0$ to $V_{CC}$
Continuous current through V <sub>CC</sub> or GND	I <sub>CC</sub> or I <sub>GND</sub>	±100	mA	
Maximum power dissipation at Ta = 25°C (in still air) *3	P <sub>T</sub>	200	mW	
Storage temperature	Tstg	-65 to 150	°C	

Notes: The absolute maximum ratings are values, which must not individually be exceeded, and furthermore, no two of which may be realized at the same time.

- 1. The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
- 2. This value is limited to 4.6 V maximum.
- 3. The maximum package power dissipation was calculated using a junction temperature of 150°C.

# **Recommended Operating Conditions**

Item	Symbol	Min	Max	Unit	Conditions
Supply voltage range	Vcc	1.2	3.6	V	
Input voltage range	VI	0	3.6	V	
Output voltage range	Vo	0	V <sub>CC</sub>	V	
		_	2		V <sub>CC</sub> = 1.2 V
		_	4	mA	V <sub>CC</sub> = 1.4 V
Output current	I <sub>OL</sub>	_	6		V <sub>CC</sub> = 1.65 V
		_	18		V <sub>CC</sub> = 2.3 V
		_	24		$V_{CC} = 3.0 \text{ V}$
Input transition rise or fall rate	Δt / Δν	0	20	ns / V	$V_{CC} = 1.2 \text{ to } 2.7 \text{ V}$
input transition rise of fail rate	Δι / Δν	0	10	115 / V	$V_{CC} = 3.3 \pm 0.3 \text{ V}$
Operating free-air temperature	Та	-40	85	°C	

Note: Unused or floating inputs must be held high or low.

#### **Electrical Characteristics**

 $(Ta = -40 \text{ to } 85^{\circ}C)$ 

Item	Symbol	V <sub>CC</sub> (V) *1	Min	Тур	Max	Unit	Test Conditions
		1.2	V <sub>CC</sub> ×0.75	_	_		
		1.4 to 1.6	V <sub>CC</sub> ×0.7		_		
	$V_{IH}$	1.65 to 1.95	V <sub>CC</sub> ×0.7		_		
Input voltage		2.3 to 2.7	1.7	_	_		
		3.0 to 3.6	2.0		_	V	
		1.2			V <sub>CC</sub> ×0.25	V	
		1.4 to 1.6			V <sub>CC</sub> ×0.3		
	$V_{IL}$	1.65 to 1.95			V <sub>CC</sub> ×0.3		
		2.3 to 2.7			0.7		
		3.0 to 3.6			0.8		
	V <sub>OL</sub>	Min to Max			0.2		$I_{OL} = 100 \mu A$
		1.2	_	_	0.3		$I_{OL} = 2 \text{ mA}$
Output voltage		1.4	_	_	0.3	- v	$I_{OL} = 4 \text{ mA}$
Output Voltage		1.65	_	_	0.3		$I_{OL} = 6 \text{ mA}$
		2.3	_	_	0.55		$I_{OL} = 18 \text{ mA}$
		3.0	_	_	0.55		$I_{OL} = 24 \text{ mA}$
Input current	I <sub>IN</sub>	3.6	_	_	±5	μΑ	$V_{IN} = 3.6 \text{ V or GND}$
Off state output current	I <sub>OZ</sub>	3.6	_	_	±5	μΑ	$V_{OUT} = V_{CC}$ or GND
Quiescent supply current	I <sub>CC</sub>	3.6		_	10	μΑ	$V_{IN} = V_{CC}$ or GND, $I_O = 0$
Output leakage current	I <sub>OFF</sub>	0	_	_	5	μА	$V_{IN}$ or $V_O = 0$ to 3.6 V
Input capacitance	C <sub>IN</sub>	3.3	_	5.0	_	pF	$V_{IN} = V_{CC}$ or GND

Note: For conditions shown as Min or Max, use the appropriate values under recommended operating conditions.

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# **Switching Characteristics**

 $V_{\rm CC} = 1.2 \ V$ 

Item	Symbol Ta = -40 to 85°C		Unit	Test Conditions	FROM	ТО		
item	Symbol	Min	Тур	Typ Max		rest Conditions	(Input)	(Output)
Propagation delay time	t <sub>LZ</sub> t <sub>ZL</sub>	_	5.0	_	ns	C <sub>L</sub> = 15 pF	Α	Ÿ

 $V_{CC} = 1.5 \pm 0.1 \text{ V}$ 

Item	Symbol	Та	Ta = -40 to 85°C		Unit	Test Conditions	FROM	ТО
Item	Syllibol	Min	Min	Min	Onne	rest conditions	(Input)	(Output)
Propagation delay time	t <sub>LZ</sub>	1.0	_	7.0	ns	C <sub>L</sub> = 15 pF	Α	Ÿ

 $V_{CC} = 1.8 \pm 0.15 \text{ V}$ 

Item	Symbol	Та	= -40 to 8	5°C	Unit	Test Conditions	FROM	ТО
item	Syllibol	Min	Тур	Max	Oilit	rest Conditions	(Input)	(Output)
Propagation delay time	t <sub>LZ</sub>	1.0	_	5.0	ns	C <sub>L</sub> = 30 pF	Α	Y

 $V_{CC}=2.5{\pm}0.2~V$ 

Item	Symbol	Та	= -40 to 8	5°C	Unit	Test Conditions	FROM	ТО
item	Syllibol	Min	Тур	Max	Oilit	rest Conditions	(Input)	(Output)
Propagation delay time	t <sub>LZ</sub>	0.5	_	3.5	ns	C <sub>L</sub> = 30 pF	А	Ÿ

 $V_{CC} = 3.3 \pm 0.3 \text{ V}$ 

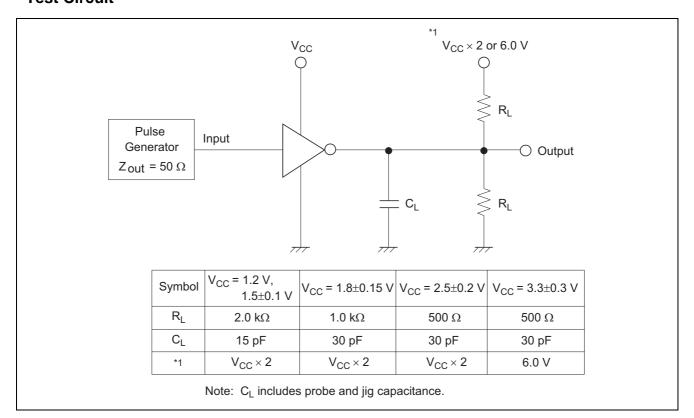
Item	Symbol	Та	= -40 to 8	5°C	Unit	Test Conditions	FROM	ТО
item	Syllibol	Min	Тур	Max	Onit	rest Conditions	(Input)	(Output)
Propagation delay time	t <sub>LZ</sub>	0.5	_	2.5	ns	C <sub>L</sub> = 30 pF	Α	Ÿ

# **Operating Characteristics**

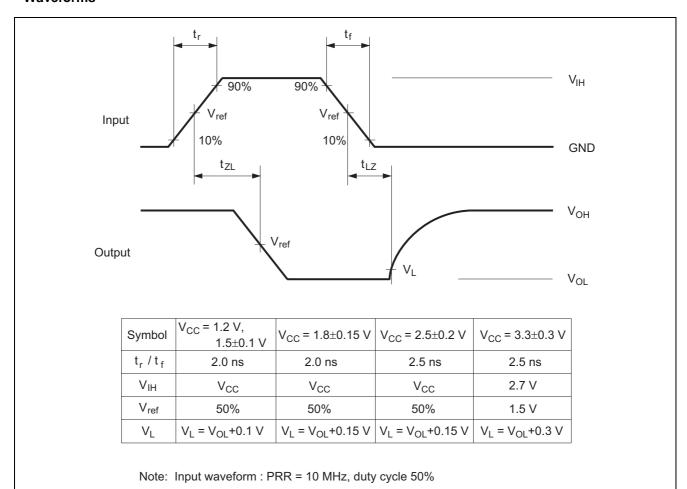
 $(Ta = 25^{\circ}C)$ 

Item	Symbol	V <sub>cc</sub> (V)	Min	Тур	Max	Unit	Test Conditions
Power dissipation capacitance C <sub>Pl</sub>	C	1.5		1.5	_		f = 10 MHz
		1.8		1.5		PF	
	OPD	2.5	_	2.0	_	ρr	
		3.3		3.0			

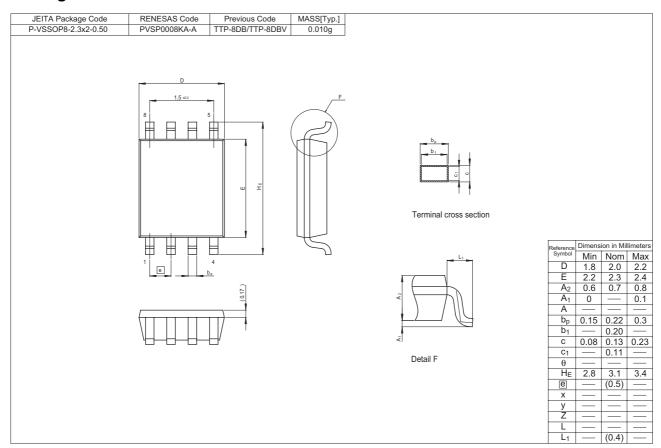
#### **Test Circuit**



#### **Waveforms**



### **Package Dimensions**



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Renesas Technology Europe Limited
Dukes Meadow, Millboard Road, Bourne End, Buckinghamshire, SL8 5FH, U.K.
Tel: <44> (1628) 585-100, Fax: <44> (1628) 585-900

Renesas Technology (Shanghai) Co., Ltd.

Neitesas Technology (offangriar) 63., Ed. Unit 204, 205, AZIACenter, No. 1233 Lujiazui Ring Rd, Pudong District, Shanghai, China 200120 Tel: <86> (21) 5877-1818, Fax: <86> (21) 6887-7898

Renesas Technology Hong Kong Ltd.
7th Floor, North Tower, World Finance Centre, Harbour City, 1 Canton Road, Tsimshatsui, Kowloon, Hong Kong Tel: <852> 2265-6688, Fax: <852> 2730-6071

**Renesas Technology Taiwan Co., Ltd.**10th Floor, No.99, Fushing North Road, Taipei, Taiwan Tel: <886> (2) 2715-2888, Fax: <886> (2) 2713-2999

Renesas Technology Singapore Pte. Ltd.
1 Harbour Front Avenue, #06-10, Keppel Bay Tower, Singapore 098632 Tel: <65> 6213-0200, Fax: <65> 6278-8001

Renesas Technology Korea Co., Ltd. Kukje Center Bldg. 18th Fl., 191, 2-ka, Hangang-ro, Yongsan-ku, Seoul 140-702, Korea Tel: <82> (2) 796-3115, Fax: <82> (2) 796-2145

Renesas Technology Malaysia Sdn. Bhd
Unit 906, Block B, Menara Amcorp, Amcorp Trade Centre, No.18, Jalan Persiaran Barat, 46050 Petaling Jaya, Selangor Darul Ehsan, Malaysia Tel: <603> 7955-9390, Fax: <603> 7955-9510

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